Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	66	(((satura$4 near3 (region or reflect$4 or mirror or absorb$4)) or sam) same ((arsenic or berryllium or proton$2) same ion))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 08:34
L2	13	(((satura$4 near3 (region or reflect$4 or mirror or absorb$4))) same ((arsenic or beryllium or proton$2) same ion))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 09:11
L3	58	((satura$4 near3 (region or reflect$4 or mirror or absorb$4)) same (arsenic or beryllium or proton$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:09
L4	2	((satura$4 near3 (region or reflect$4 or mirror or absorb$4)) same (arsenic or beryllium or proton$2) same energy)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 09:12
L5	3006	((satura$4 near3 (region or reflect$4 or mirror or absorb$4)) same (Be or As or arsenic or beryllium or proton$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:09
L6	1040	((satura$4 near3 (mirror or absorb$4)) same (Be or As or arsenic or beryllium or proton$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:10
L8	48	(((satura$4 near3 (mirror or absorb$4)) same (Be or As or arsenic or beryllium or proton$2)) same ion)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:10
L12	1	((saturab$4 near3 (reflect$4 or mirror or absorb$4)) or sam) and (passive with (modelock$ or (mode near2 lock$3))) and ((proton or arsenic or beryllium or beryl$1ium) near3 implant$4)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L13	1	((saturab$4 near3 (reflect$4 or mirror or absorb$4)) or sam) and (passive with (modelock$ or (mode near2 lock$3))) and ((proton or arsenic or beryllium or beryl$1ium) SAME implant$4)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L14	1	((saturab$4 near3 (reflect$4 or mirror or absorb$4)) or sam) and (passive with (modelock$ or (mode near2 lock$3))) and ((proton or arsenic or beryllium or beryl$1ium) and (ion near4 implant$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L15	4	((saturab$4 near3 (reflect$4 or mirror or absorb$4))) and ((proton or arsenic or beryllium or beryl$1ium) and (ion near4 implant$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:35
L16	2	((saturab$4 near3 (reflect$4 or mirror or absorb$4))) and ((proton or arsenic or beryllium or beryl$1ium) SAME (ion near4 implant$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:21

L17	29	((saturab$4 near3 (reflect$4 or mirror or absorb$4)) SAME (anti near2 reflect$3))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:25
L18	1	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 material) same (mult$4 or plural$4 or more) near3 relax$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:53
L19	3	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 material) and (mult$4 or plural$4 or more) near3 relax$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:27
L20	1	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 material) same (mult$4 or plural$4 or more) same relax$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:26
L21	4	((saturab$4 near3 (reflect$4 or mirror or absorb$4))) and ((proton or arsenic or beryllium or beryl$1ium) and (ion near4 (implant$4 or introduct$4)))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:36
L22	1	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 material) same (mult$4 or plural$4 or more) near3 (nonstress or ease or loosen or unband or unlax or unwind or unstress or free or relax$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:57
L23	2	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 (material or element or film)) same (mult$4 or plural$4 or more) near3 (nonstress or ease or loosen or unband or unlax or unwind or unstress or free or relax$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:06
L24	31	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or ease or loosen or unband or unlax or unwind or unstress or free or relax$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:05
L25	13	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or ease or loosen or unband or unlax or unwind or unstress or relax$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:05
L26	13	(saturab$4 near3 (reflect$4 or mirror or absorb$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or loosen or unband or unlax or unwind or unstress or relax$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:10